

RoHS COMPLIANT

GREEN

(5-2008)

Vishay Semiconductors

High Power Infrared Emitting Diode, 940 nm, GaAlAs/GaAs



DESCRIPTION

VSML3710 is an infrared, 940 nm emitting diode in GaAlAs/GaAs technology with high radiant power, molded in a PLCC-2 package for surface mounting (SMD).

FEATURES

- · Package type: surface mount
- Package form: PLCC-2
- Dimensions (L x W x H in mm): 3.5 x 2.8 x 1.75
- Peak wavelength: $\lambda_p = 940 \text{ nm}$
- High reliability
- · High radiant power
- · High radiant intensity
- Angle of half intensity: $\phi = \pm 60^{\circ}$
- · Low forward voltage
- Suitable for high pulse current operation
- · Good spectral matching with Si photodetectors
- Package matched with IR emitter series VEMT3700
- Floor life: 168 h, MSL 3, acc. J-STD-020
- · Lead (Pb)-free reflow soldering
- AEC-Q101 gualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- · Find out more about Vishay's Automotive Grade Product requirements at: www.vishay.com/applications

APPLICATIONS

- IR emitter in photointerrupters, sensors and reflective sensors
- IR emitter in low space applications
- Household appliance
- · Tactile keyboards

PRODUCT SUMMARY

PRODUCT SOMMANT				
COMPONENT	l _e (mW/sr)	φ (deg)	λ _p (nm)	t _r (ns)
VSML3710	8	± 60	940	800

Note

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSML3710-GS08	Tape and reel	MOQ: 7500 pcs, 1500 pcs/reel	PLCC-2		
VSML3710-GS18	Tape and reel	MOQ: 8000 pcs, 8000 pcs/reel	PLCC-2		

Note

MOQ: minimum order quantity

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

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For technical questions, contact: emittertechsupport@vishay.com

VSML3710

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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	5	V	
Forward current		I _F	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I _{FM}	200	mA	
Surge forward current	t _p = 100 μs	I _{FSM}	1	А	
Power dissipation		Pv	160	mW	
Junction temperature		Тj	100	°C	
Operating temperature range		T _{amb}	- 40 to + 85	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	Acc. figure 11, J-STD-020	T _{sd}	260	°C	
Thermal resistance junction/ambient	J-STD-051, soldered on PCB	R _{thJA}	250	K/W	

Note $T_{amb} = 25$ °C, unless otherwise specified

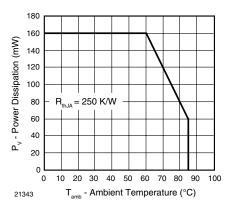


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

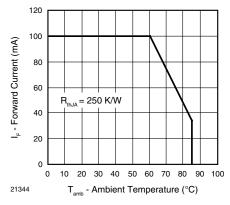


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 100 mA, t _p = 20 ms	V _F		1.35	1.6	V
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	V _F		2.6	3	V
Temperature coefficient of V_F	I _F = 1 mA	TK _{VF}		- 1.8		mV/K
Reverse current	V _R = 5 V	I _R			100	μA
Junction capacitance	V _R = 0 V, f = 1 MHz, E = 0	Cj		25		pF
Dedient intereit.	I _F = 100 mA, t _p = 20 ms	l _e	4	8	20	mW/sr
Radiant intensity	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	l _e		60		mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	фе		35		mW
Temperature coefficient of ϕ_{e}	I _F = 100 mA	ΤKφ _e		- 0.6		%/K
Angle of half intensity		φ		± 60		deg
Peak wavelength	I _F = 100 mA	λρ		940		nm
Spectral bandwidth	I _F = 100 mA	Δλ		50		nm
Temperature coefficient of λ_p	I _F = 100 mA	ΤΚλ _ρ		0.2		nm/K
Rise time	I _F = 20 mA	t _r		800		ns
	I _F = 1 A	t _r		500		ns
Fall time	I _F = 20 mA	t _f		800		ns
	I _F = 1 A	t _f		500		ns
Virtual source diameter		d		0.44		mm

Note

T_{amb} = 25 °C, unless otherwise specified

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BASIC CHARACTERISTICS

 $T_{amb} = 25$ °C, unless otherwise specified

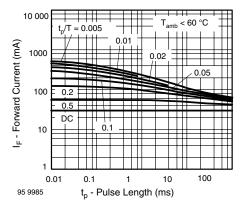


Fig. 3 - Pulse Forward Current vs. Pulse Duration

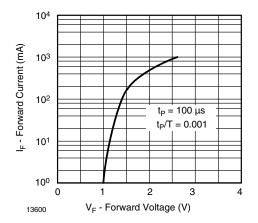


Fig. 4 - Forward Current vs. Forward Voltage

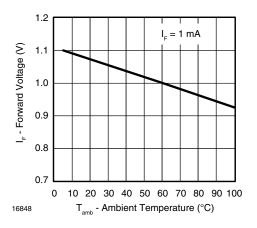


Fig. 5 - Forward Voltage vs. Ambient Temperature

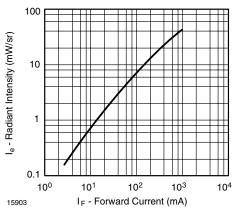


Fig. 6 - Radiant Intensity vs. Forward Current

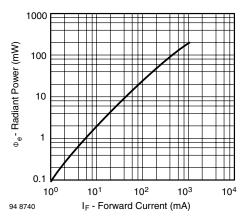


Fig. 7 - Radiant Power vs. Forward Current

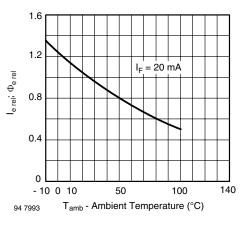


Fig. 8 - Relative Radiant Intensity/Power vs. Ambient Temperature

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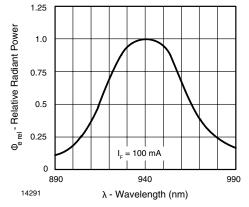
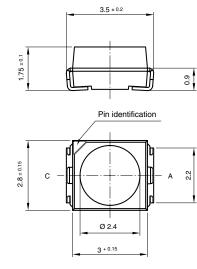


Fig. 9 - Relative Radiant Power vs. Wavelength







SOLDER PROFILE

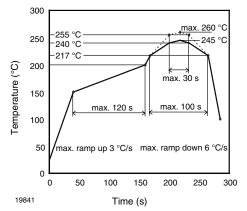
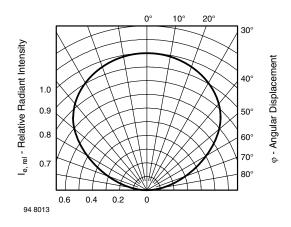
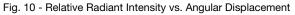
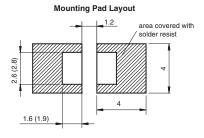


Fig. 11 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020









DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label: Floor life: 168 h Conditions: T_{amb} < 30 °C, RH < 60 % Moisture sensitivity level 3, acc. to J-STD-020.

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.



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TAPE AND REEL

PLCC-2 components are packed in antistatic blister tape (DIN IEC (CO) 564) for automatic component insertion. Cavities of blister tape are covered with adhesive tape.

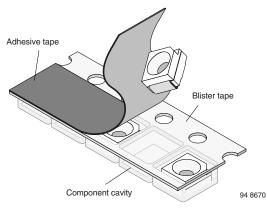


Fig. 12 - Blister Tape

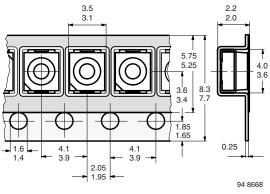


Fig. 13 - Tape Dimensions in mm for PLCC-2

MISSING DEVICES

A maximum of 0.5 % of the total number of components per reel may be missing, exclusively missing components at the beginning and at the end of the reel. A maximum of three consecutive components may be missing, provided this gap is followed by six consecutive components.

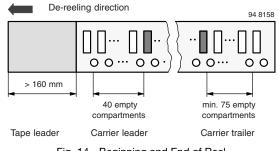


Fig. 14 - Beginning and End of Reel

Document Number: 81300 Rev. 1.4, 03-Nov-09 The tape leader is at least 160 mm and is followed by a carrier tape leader with at least 40 empty compartments. The tape leader may include the carrier tape as long as the cover tape is not connected to the carrier tape. The least component is followed by a carrier tape trailer with a least 75 empty compartments and sealed with cover tape.

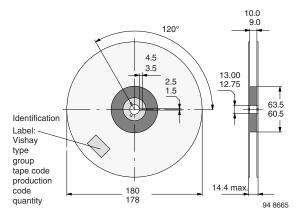
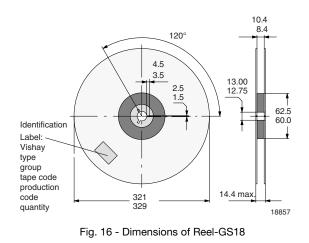


Fig. 15 - Dimensions of Reel-GS08



COVER TAPE REMOVAL FORCE

The removal force lies between 0.1 N and 1.0 N at a removal speed of 5 mm/s. In order to prevent components from popping out of the blisters, the cover tape must be pulled off at an angle of 180° with regard to the feed direction.



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